

430-02  
P. H. H. B. B.  
PATENT APPLICATION

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of

Mitsutoshi MIYASAKA

Rule 53(b) Divisional of  
Application No.: 09/400,303

Filed: March 19, 2002

Docket No.: 038839.02

For: A METHOD FOR FORMING CRYSTALLINE SEMICONDUCTOR LAYERS, A  
METHOD FOR FABRICATING THIN FILM TRANSISTORS, AND A METHOD FOR  
FABRICATING SOLAR CELLS AND ACTIVE MATRIX LIQUID CRYSTAL  
DEVICES

PRELIMINARY AMENDMENT

Assistant Commissioner of Patents  
Washington, D. C. 20231

Sir:

Prior to initial examination, please amend the above-identified application as follows:

IN THE SPECIFICATION:

Page 1, line 1, delete in its entirety.

Page 1, between lines 5 and 6, insert the following centered heading:

BACKGROUND OF THE INVENTION

Page 1, line 6:

Field of The Invention

Page 1, line 12:

Description of the Related Art

Page 3, line 25:

SUMMARY OF THE INVENTION

2006 FEB 03 10:00